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**APPLICANTS: Lin Wen; Pearce Charles; <i>2803</i> <i>MALDONADO</i>					
**CONTINUING DATA VERIFIED:					
** FOREIGN APPLICATIONS VERIFIED:					
PG-PUB	DO NOT PUBLISH <input type="checkbox"/>	RESCIND <input type="checkbox"/>			
Foreign priority claimed 35 USC 119 conditions met Verified and Acknowledged Examiner's initials		<input type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> yes <input type="checkbox"/> no	ATTORNEY DOCKET NO. LIN 11-34		
TITLE : Semiconductor device having a doped lattice matching layer and a method of manufacture therefor					
U.S. DEPT. OF COMM/PAT & TEL-FTC-4567 (Rev. 12-2)					

DISCLAIMER

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